

GDT2R75-T5454 Thru GDT2R600-T5454

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GDT2R75-T5454 Thru GDT2R600-T5454

Gas Discharge Tube Surge 5KA(8/20 μ s)

Features

- Extremely small size.
- Extremely fast response time.
- Excellent SMD handling
- Stable performance over life.
- Very low capacitance.
- High insulation resistance.
- Storage and operating temperature -40 ~ +125°C.
- UL-identification.
- Lead-free parts meet RoHS requirements.
- Suffix "-H" indicates Halogen free parts, ex. GDT2R75-T5454-H.

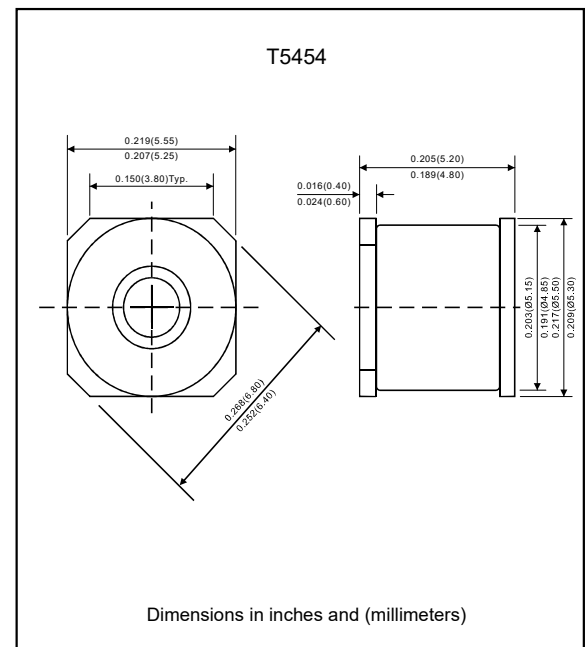
Applications

- Splitter.
- PCI Cards .
- Line cards.

Mechanical data

- Meets MSL level 1, per J-STD-020, LF Maximum peak 260°C.
- Case : Molded plastic, T5454.
- Terminals : Solder plated, solder able per J-STD-002.
- Polarity : Indicated by cathode band.
- Mounting Position : Any.

Package outline



Electrical specifications

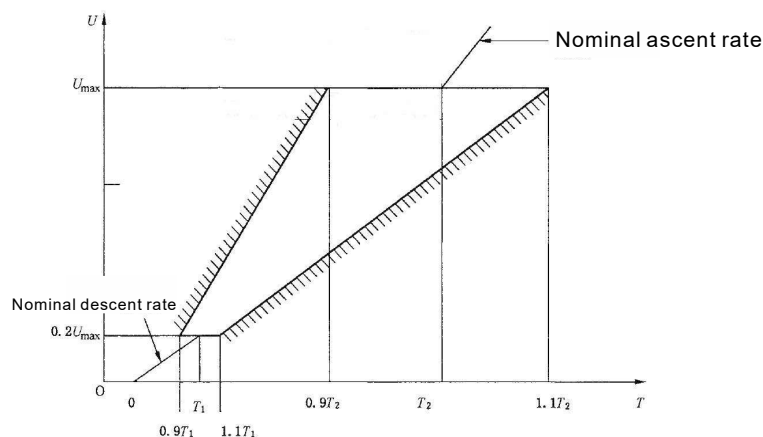
Parameter	GDT2R75-T5454	GDT2R90-T5454	GDT2R150-T5454	GDT2R230-T5454	GDT2R300-T5454	GDT2R350-T5454	GDT2R400-T5454	GDT2R470-T5454	GDT2R600-T5454	Unit
Impulse spark-over voltage (100V/s)	±30	±30	±20	±20	±20	±20	±20	±20	±20	%
Impulse breakdown voltage (1KV/ μ s)	600	600	600	800	850	950	1000	1100	1200	V
Discharge current (8/20 μ s, 10 times)	5	5	5	5	5	5	5	5	5	KA
AC Discharge current (50Hz, 1s)	5	5	5	5	5	5	5	5	5	A
Impulse life (10/1000 μ s, 10A)	100	100	100	100	100	100	100	100	100	Times
Minimum insulation resistance	50	50	100	100	100	100	100	100	100	DC(V)
	1	1	1	1	1	1	1	1	1	G Ω
Max. Capacitance (1MHz)	1	1	1	1	1	1	1	1	1	pF

Marking

Type number	Marking code
GDT2R75-T5454	2R75
GDT2R90-T5454	2R90
GDT2R150-T5454	2R150
GDT2R230-T5454	2R230
GDT2R300-T5454	2R300
GDT2R350-T5454	2R350
GDT2R400-T5454	2R400
GDT2R470-T5454	2R470
GDT2R600-T5454	2R600

GDT2R75-T5454 Thru GDT2R600-T5454**Electrode arrester**

DC breakdown voltage



8/20us, Test wave

$$T_1 = 1.25T = 8\mu s \pm 20\%$$

$$T_2 = 20\mu s \pm 20\%$$

10/700us, Test Wave

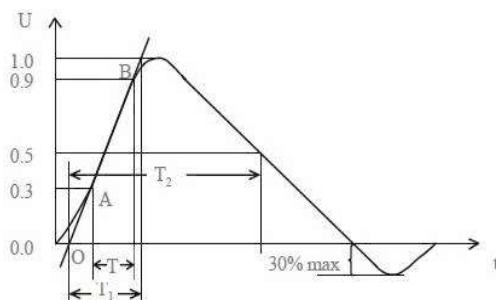
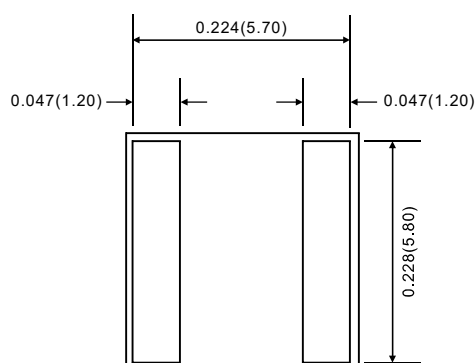
$$T_1 = 1.67T = 10\mu s \pm 20\%$$

$$T_2 = 700\mu s \pm 20\%$$

10/1000us, Test Wave

$$T_1 = 1.67T = 10\mu s \pm 20\%$$

$$T_2 = 1000\mu s \pm 20\%$$

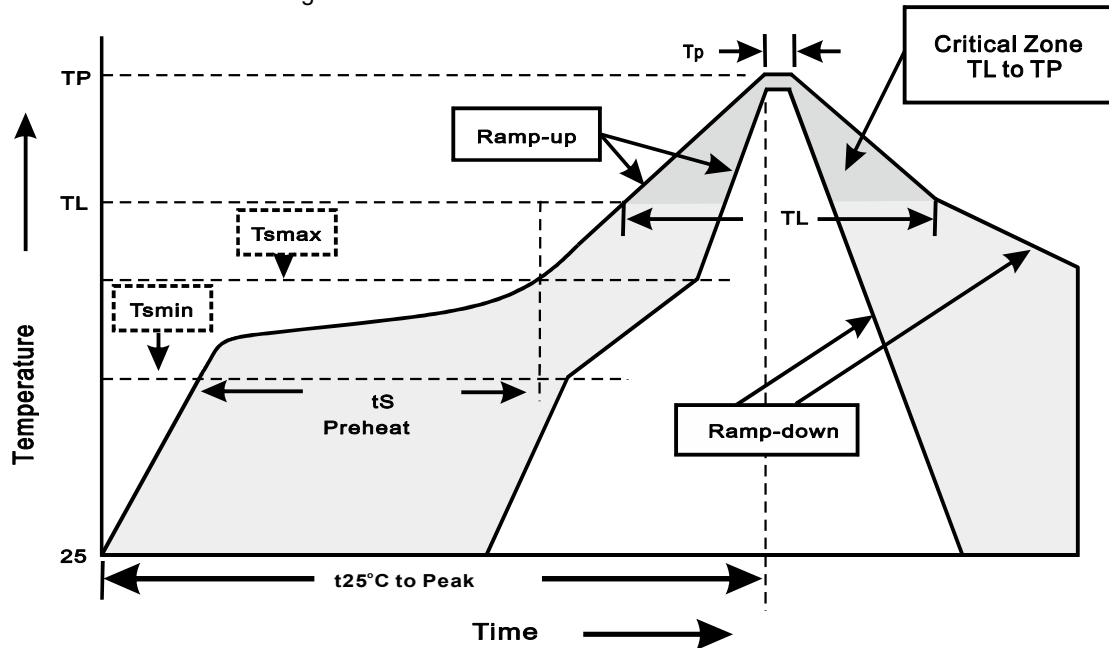
**Suggested solder pad layout**

Dimensions in inches and (millimeters)

GDT2R75-T5454 Thru GDT2R600-T5454

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{Smin}) -Temperature Max(T _{Smax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{Smax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes